TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM6N35FE

- High-Speed Switching Applications
- Analog Switch Applications
- 1.2-V drive
- N-ch 2-in-1
- Low ON-resistance: R_{on} = 20 Ω (max) (@V_{GS} = 1.2 V)

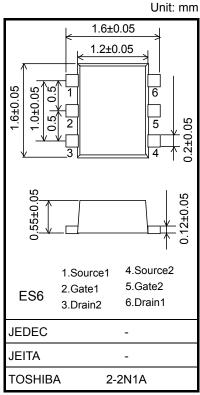
: R_{on} = 8 Ω (max) (@V_{GS} = 1.5 V)

: R_{on} = 4 Ω (max) (@V_{GS} = 2.5 V)

: R_{on} = 3 Ω (max) (@V_{GS} = 4.0 V)

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	20	V	
Gate-source voltage		V _{GSS}	±10	V	
Drain current	DC	ID	180	mA	
	Pulse	I _{DP}	360	IIIA	
Drain power dissipation		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature		T _{stg}	-55 to 150	°C	



Weight: 3.0 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

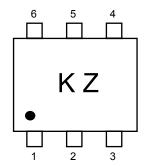
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

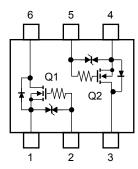
Mounted on an FR4 board

(25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 0.135 mm² \times 6)

Marking



Equivalent Circuit (top view)



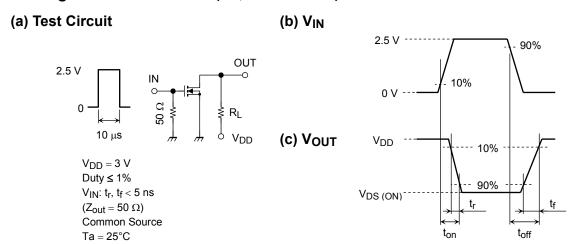
Start of commercial production 2008-02

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Charae	cteristics	Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±10	μА
Drain-source brea	ıkdown voltage	V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0V$		20	_	_	V
Drain cutoff curren	ıt	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$		_	_	1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$		0.4	_	1.0	>
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 50 \text{ mA}$	(Note 2)	115	_	_	mS
Drain gaurae ON registance		R _{DS} (ON)	$I_D = 50$ mA, $V_{GS} = 4$ V	(Note 2)	_	1.5	3	Ω
			$I_D = 50$ mA, $V_{GS} = 2.5$ V	(Note 2)	_	2	4	
Drain–source ON-resistance	$I_D = 5 \text{ mA}, V_{GS} = 1.5 \text{ V}$		(Note 2)	_	3	8		
			$I_D = 5 \text{ mA}, V_{GS} = 1.2 \text{ V}$	(Note 2)	_	5	20	
Input capacitance	out capacitance C _{iss}					9.5	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS}=3~V,~V_{GS}=0V,~f=1~MHz$		_	4.1	_	
Output capacitance		Coss		_	9.5	_		
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 50 \text{ mA},$		_	115	_	no
	Turn-off time	t _{off}	$V_{GS} = 0$ to 2.5 V		_	300	_	ns
Drain-source forward voltage		V _{DSF}	$I_D = -180 \text{ mA}, V_{GS} = 0V$	(Note 2)	_	-0.9	-1.2	V

Note 2: Pulse test

Switching Time Test Circuit (Q1, Q2 Common)



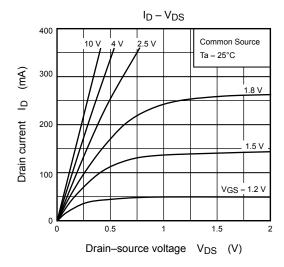
Usage Considerations

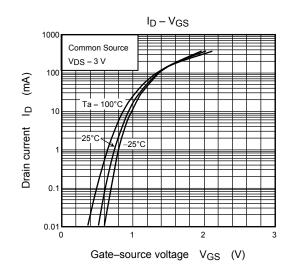
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the SSM6N35FE). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

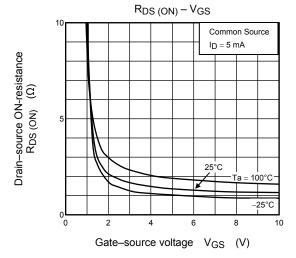
Take this into consideration when using the device.

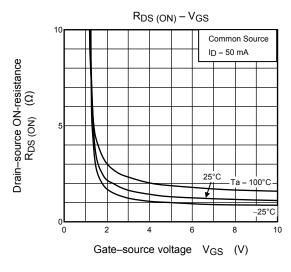
Handling Precaution

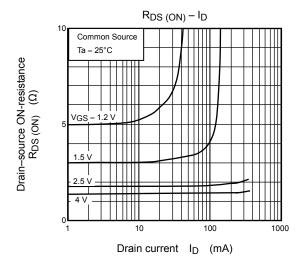
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

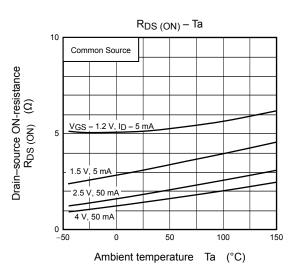




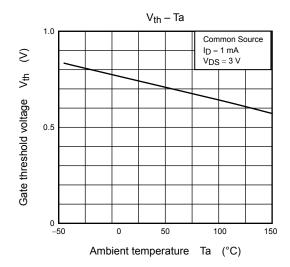


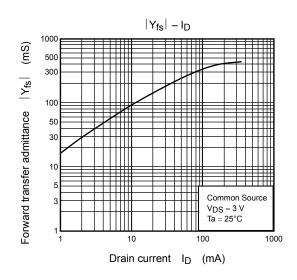


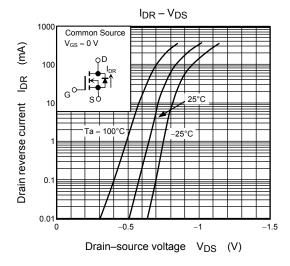


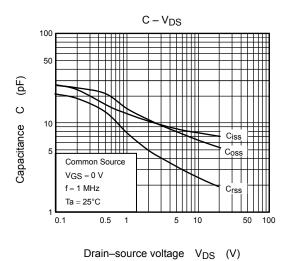


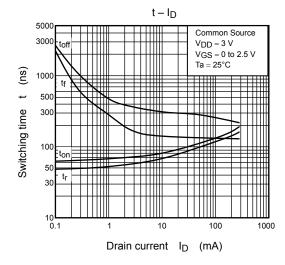
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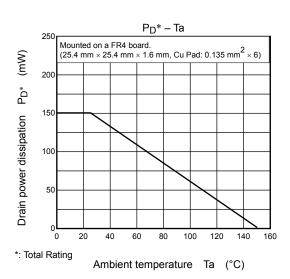












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